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Inventor(s)

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Qian; You et al.

Method of making acoustic devices with directional reinforcement

Abstract

A method of making an acoustic sensor includes forming or providing a mold having one or more grooves extending in a direction of the length of the mold to a distal end of the mold. The method also includes forming or depositing a structure having one or more piezoelectric layers over the top surface of the mold to define a beam with a proximal portion and a distal portion, the distal portion having a corrugated section including one or more grooves that correspond to the one or more grooves of the mold. The method also includes forming or applying an electrode to the proximal portion of the structure and releasing the structure from the mold to form one or more cantilever beams. The corrugated section inhibits bending of the corrugated section along the length of the distal portion of the structure when the acoustic sensor is subjected to sound pressure.

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Background/Summary

INCORPORATION BY REFERENCE TO ANY PRIORITY APPLICATIONS

(1) Any and all applications for which a foreign or domestic priority claim is identified in the Application Data Sheet as filed with the present application are hereby incorporated by reference under 37 CFR 1.57.

BACKGROUND

Field

(2) The present disclosure is directed to acoustic devices, such as piezoelectric microelectromechanical systems (MEMS) microphones, and in particular to methods of making acoustic devices with directional reinforcement.

Description of the Related Art

- (3) A MEMS microphone is a micro-machined electromechanical device used to convert sound pressure (e.g., voice sound) to an electrical signal (e.g., voltage). MEMS microphones are widely used in mobile devices, headsets, smart speakers and other voice-interface devices or systems. Conventional capacitive MEMS microphones suffer from high power consumption (e.g., large bias voltage) and reliability, for example when used in a harsh environment (e.g., when exposed to dust and/or water).
- (4) Piezoelectric MEMS microphones have been used to address the deficiencies of capacitive MEMS microphones. Piezoelectric MEMS microphones offer a constant listening capability while consuming almost no power (e.g., no bias voltage is needed), are robust and immune to water and dust contamination. Existing piezoelectric MEMS microphones include cantilever MEMS structures, and are mostly based on sputter-deposited thin film piezoelectric structure. Such thin piezoelectric film suffers from large residual stress and stress gradient across the film thickness after deposition which results in sensitivity degradation and variation. The cantilever MEMS structure suffers from poor low-frequency roll-off control as the gap between cantilevers varies due to cantilever deflection induced by residual stress and stress gradient of the piezoelectric film for a single or multiple films stacked together. Additionally, the cantilever MEMS structure with gap control mechanism can have a complex structure that results in higher manufacturing costs and poor reliability performance.

SUMMARY

(5) Accordingly, there is a need for an improved acoustic device with directional reinforcement that

can be used, for example, in piezoelectric MEMS microphones and do not suffer the deficiencies in existing MEMS cantilever structures.

- (6) In accordance with one aspect of the disclosure, an acoustic sensor (e.g., for use in a piezoelectric MEMS microphone) is provided that includes a substrate and a cantilever beam attached to the substrate. The cantilever beam has a proximal portion attached to the substrate and a distal portion that extends from the proximal portion to a free end of the beam, the beam extending in a first direction between the proximal portion and the free end, the distal portion of the beam having a corrugated section including one or more grooves that extend generally in the first direction. Sound pressure exerted on the beam causes the beam, including the corrugated section to bend. The corrugated section inhibits bending along the length of the distal portion when the acoustic sensor is subjected to sound pressure. An electrode is disposed on or in the proximal portion of the beam.
- (7) In accordance with another aspect of the disclosure, a piezoelectric sensor for a piezoelectric MEMS microphone is provided. The sensor comprises a substrate and a cantilever beam. The cantilevered beam has a proximal portion attached to the substrate and a distal portion that extends from the proximal portion to a free end of the beam. The beam extends in a first direction between the proximal portion and the free end, the distal portion of the beam having a corrugated section including one or more grooves that extend generally in the first direction. An electrode is disposed on or in the proximal portion of the beam.
- (8) In accordance with another aspect of the disclosure, a piezoelectric MEMS microphone is provided. The microphone comprises a substrate and a plurality of piezoelectric sensors movably coupled to the substrate. Each of the piezoelectric sensors are spaced apart from an adjacent piezoelectric sensor by a gap. Each piezoelectric sensor includes a cantilever beam having a proximal portion attached to the substrate and a distal portion that extends from the proximal portion to a free end of the beam. The beam extends in a first direction between the proximal portion and the free end. The distal portion of the beam has a corrugated section including one or more grooves that extend generally in the first direction, and an electrode disposed on or in the proximal portion of the beam. The plurality of piezoelectric sensors are configured to deflect when subjected to sound pressure.
- (9) In accordance with another aspect of the disclosure, an audio subsystem is provided. The audio subsystem comprises an audio codec and one or more piezoelectric MEMS microphones in communication with the audio codec. Each microphone includes a substrate and a plurality of piezoelectric sensors movably coupled to the substrate. Each of the piezoelectric sensors are spaced apart from an adjacent piezoelectric sensor by a gap. Each piezoelectric sensor includes a cantilever beam having a proximal portion attached to the substrate and a distal portion that extends from the proximal portion to a free end of the beam. The beam extends in a first direction between the proximal portion and the free end. The distal portion of the beam has a corrugated section including one or more grooves that extend generally in the first direction, and an electrode disposed on or in the proximal portion of the beam.
- (10) In accordance with another aspect of the disclosure, an electronic device is provided. The electronic device comprises a processor and an audio subsystem that communicates with the processor. The audio subsystem comprises one or more piezoelectric MEMS microphones on a substrate layer. Each microphone includes a substrate and a plurality of piezoelectric sensors movably coupled to the substrate. Each of the piezoelectric sensors are spaced apart from an adjacent piezoelectric sensor by a gap. Each piezoelectric sensor includes a cantilevered beam having a proximal portion attached to the substrate and a distal portion that extends from the proximal portion to a free end of the beam. The beam extends in a first direction between the proximal portion and the free end. The distal portion of the beam has a corrugated section including one or more grooves that extend generally in the first direction, and an electrode disposed on or in the proximal portion of the beam.

- (11) In accordance with another aspect of the disclosure, a method of making an acoustic sensor (e.g., a piezoelectric sensor for a piezoelectric MEMS microphone) is provided. The method comprises forming or providing a mold extending along a length and having one or more grooves in a top surface of the mold, the one or more grooves extending in a direction of the length of the mold to a distal end of the mold. The method also comprises forming or depositing a structure having one or more piezoelectric layers over the top surface of the mold to define a beam with a proximal portion and a distal portion, the distal portion having a corrugated section including one or more grooves that correspond to the one or more grooves of the mold. The method further comprises releasing the structure from the mold to form a cantilever.
- (12) In accordance with another aspect of the disclosure, a method of making an electronic device is provided. The method comprises forming or providing a printed circuit board that includes a substrate layer. The method also comprises forming or providing one or more piezoelectric microelectromechanical systems microphones via a process comprising (a) forming or providing a mold extending along a length and having one or more grooves in a top surface of the mold, the one or more grooves extending in a direction of the length of the mold to a distal end of the mold, (b) forming or depositing a structure having one or more piezoelectric layers over the top surface of the mold to define a beam with a proximal portion and a distal portion, the distal portion having a corrugated section including one or more grooves that correspond to the one or more grooves of the mold, (c) releasing the structure from the mold, and (d) leaving a part of the structure attached to a substrate in a cantilevered manner to form a cantilever beam that deflects when subjected to sound pressure. The method also comprises mounting the one or more piezoelectric microelectromechanical systems microphones on the printed circuit board.

Description

BRIEF DESCRIPTION OF THE DRAWINGS

- (1) FIG. **1** is a schematic diagram of an audio subsystem.
- (2) FIG. **2**A is a schematic diagram of an electronic device.
- (3) FIG. **2**B is a schematic diagram of a wireless electronic device.
- (4) FIG. **3**A is a schematic top view of a piezoelectric MEMS microphone.
- (5) FIG. **3**B is a schematic side view of the piezoelectric MEMS microphone of FIG. **3**A.
- (6) FIG. **4**A is a schematic top view of a piezoelectric MEMS microphone.
- (7) FIG. **4**B is a schematic side view of the piezoelectric MEMS microphone of FIG. **4**A.
- (8) FIG. **5** is a graph of sensitivity versus frequency for the piezoelectric MEMS microphones in FIGS. **3**A and **4**A.
- (9) FIG. **6** is a schematic partial side view of a piezoelectric sensor used in a piezoelectric MEMS microphone.
- (10) FIG. 7A is a schematic top view of a piezoelectric sensor.
- (11) FIG. 7B is a schematic side view of the piezoelectric sensor of FIG. 7A.
- (12) FIG. 7C is a schematic cross-sectional view of the piezoelectric sensor of FIG. 7A along line 7C-7C in FIG. 7A.
- (13) FIG. 7D is a schematic cross-sectional view of a piezoelectric sensor.
- (14) FIG. 7E is a schematic cross-sectional view of a piezoelectric sensor.
- (15) FIG. 8 are images of displacement in various piezoelectric sensor designs.
- (16) FIG. **9** is a graph of total displacement versus length for the piezoelectric sensor designs in FIG. **8**.
- (17) FIG. **10** is a graph of voltage versus frequency for the piezoelectric sensor designs in FIG. **8**.
- (18) FIG. **11**A is a cross-sectional side view of one step in the manufacture of a piezoelectric sensor.

- (19) FIG. **11**B is a cross-sectional side view of another step in the manufacture of a piezoelectric sensor.
- (20) FIG. **11**C is a cross-sectional side view of another step in the manufacture of a piezoelectric sensor.
- (21) FIG. **12**A is a schematic top view of a piezoelectric sensor.
- (22) FIG. **12**B is a graph of total displacement versus length for the piezoelectric sensor of FIG. **12**A.
- (23) FIG. **13**A is a schematic top view of a piezoelectric sensor.
- (24) FIG. **13**B is a graph of total displacement versus length for the piezoelectric sensor of FIG. **13**A.
- (25) FIGS. **14**A-**14**K are schematic views of a corrugated section in a piezoelectric sensor.
- (26) FIG. **15**A is a top view of a piezoelectric sensor.
- (27) FIG. **15**B is a cross-sectional side view of a step in the manufacture of a piezoelectric sensor.
- (28) FIG. **15**C is a cross-sectional side view of another step in the manufacture of a piezoelectric sensor.

DETAILED DESCRIPTION

- (29) The following detailed description of certain embodiments presents various descriptions of specific embodiments. However, the innovations described herein can be embodied in a multitude of different ways, for example, as defined and covered by the claims. In this description, reference is made to the drawings were like reference numerals can indicate identical or functionally similar elements. It will be understood that elements illustrated in the figures are not necessarily drawn to scale. Moreover, it will be understood that certain embodiments can include more elements than illustrated in a drawing and/or a subset of the elements illustrated in a drawing. Further, some embodiments can incorporate any suitable combination of features from two or more drawings. (30) FIG. 1 is a schematic diagram of an audio subsystem 300. The audio subsystem 300 can include one or more microphones 10, 10A. In one implementation, at least one of the microphone(s) 10, 10A can communicate with an audio codec 301, which can control the operation of the microphone(s) 10, 10A. The audio codec 301 can also communicate with a speaker 302 and control the operation of the speaker 302.
- (31) FIG. **2**A is a schematic diagram of an electronic device **200** that includes the audio subsystem **300**. The electronic device **200** can optionally have one or more of a processor **210**, a memory **220**, a user interface **230**, a battery **240** (e.g., direct current (DC) battery) and a power management module **250**. Other additional components, such a display and keyboard can optionally be connected to the processor **210**. The battery **240** can provide power to the electronic device **200**. (32) It should be noted that, for simplicity, only certain components of the electronic device **200** are illustrated herein. The control signals provided by the processor **210** control the various components within the electronic device **200**.
- (33) The processor **210** communicates with the user interface **220** to facilitate processing of various user input and output (I/O), such as voice and data. As shown in FIG. **2**A, the processor **210** communicates with the memory **220** to facilitate operation of the electronic device **200**.
- (34) The memory **220** can be used for a wide variety of purposes, such as storing data and/or instructions to facilitate the operation of the electronic device **200** and/or to provide storage of user information.
- (35) The power management system or module **250** provides a number of power management functions of the electronic device **200**. In certain implementations, the power management system **250** includes a PA supply control circuit that controls the supply voltages of power amplifiers. For example, the power management system **250** can change the supply voltage(s) provided to one or more power amplifiers to improve efficiency.
- (36) As shown in FIG. 2A, the power management system 250 receives a battery voltage from the

battery **240**. The battery **240** can be any suitable battery for use in the electronic device **200**, including, for example, a lithium-ion battery.

- (37) FIG. 2B is a schematic diagram of a wireless electronic device **200**′ The wireless electronic device **200**′ is similar to the electronic device **200** in FIG. 2A. Thus, reference numerals used to designate the various components of the wireless electronic device **200**′ are identical to those used for identifying the corresponding components of the electronic device **200** in FIG. **2**A. Therefore, the structure and description above for the various features of the electronic device **200** in FIG. **2**A are understood to also apply to the corresponding features of the wireless electronic device **200**′ in FIG. **2**B, except as described below.
- (38) The wireless electronic device **200**′ differs from the electronic device **200** in that it also includes a transceiver **260** that communicates (e.g., two-way communication) with the processor **210**. Signals, data and/or information received (e.g., wirelessly) by the transceiver **260** (e.g., from a remote electronic device, such a smartphone, tablet computer, etc.) is communicated to the processor **210**, and signals, data and/or information provided by the processor is communicated (e.g., wirelessly) by the transceiver **260** (e.g., to a remote electronic device). Further, the function of the transceiver **260** can be integrated into separate transmitter and receiver components. (39) The wireless electronic device **200**′ can be used to communicate using a wide variety of communications technologies, including, but not limited to, 2G, 3G, 4G (including LTE, LTE-Advanced, and LTE-Advanced Pro), 5G NR, WLAN (for instance, Wi-Fi), WPAN (for instance, Bluetooth and ZigBee), WMAN (for instance, WiMax), and/or GPS technologies. (40) The transceiver **260** generates RF signals for transmission and processes incoming RF signals received from antennas. It will be understood that various functionalities associated with the transmission and receiving of RF signals can be achieved by one or more components that are collectively represented in FIG. 2B as the transceiver **260**. In one example, separate components (for instance, separate circuits or dies) can be provided for handling certain types of RF signals. (41) The processor **210** provides the transceiver **260** with digital representations of transmit signals, which the transceiver **260** processes to generate RF signals for transmission. The processor **210** also processes digital representations of received signals provided by the transceiver **260**. (42) Piezoelectric MEMS Microphone
- (43) FIGS. 3A-3B show a piezoelectric microelectromechanical systems (MEMS) microphone 10 (hereinafter the "microphone"). The microphone **10** has a substrate **12**. The substrate **12** is optionally made of Silicon and may optionally have additional dielectric, metallic or semiconductor films deposited on it. The microphone 10 can have one or more piezoelectric sensors 14 (hereinafter "sensors") anchored to the substrate **12** in cantilever form with a gap **16** between adjacent sensors 14. The microphone 10 converts an acoustic signal to an electrical signal when a sound wave vibrates the sensors **14**. The sensors **14** can be made from one or more layers of piezoelectric material. Optionally, the sensors **14** can be made at least in part of Aluminum Nitride (AlN). In another implementation, the sensors **14** can optionally be made at least in part of Scandium Aluminum Nitride (ScAlN). In other implementations, the sensors **14** can optionally be made at least in part of one of the following piezoelectric materials: Zinc Oxide (ZnO), Lead Zirconate Titanate (PZT), Polyvinylidene fluoride (PVDF, Lithium Niobate (LiNbO.sub.3), Barium Titanate (BaTiO.sub.3), Lead Magnesium Niobate-Lead Titanate (PMN-PT). The sensors **14** can include an electrode, which can optionally be made of aluminum (Al), molybdenum (Mo), titanium (Ti), titanium nitride (TiN), platinum (Pt), tantalum (Ta) or ruthenium (Ru), in some implementations. The gaps 16 between the sensors 14 allow the sensors 14 to freely move, for airflow F to pass therethrough, and balance the pressure between both sides of the sensors **14**. The gap **16** can be about 100-500 nm wide. The sensors **14** are preferably planar (e.g., flat), but are generally not completely flat due to a material internal stress gradient in the sensors **14**. (44) FIGS. **4**A-**4**B show a piezoelectric MEMS microphone **10**A (hereinafter "microphone"). The microphone **10**A is similar to the microphone **10** in FIGS. **3**A-**3**B. Thus, references numerals used

to designate the various components of the microphone **10**A are identical to those used for identifying the corresponding components of the microphone **10** in FIGS. **3**A-**3**B, except that an "A" has been added to the numerical identifier. Therefore, the structure and description for the various features of the microphone **10** in FIGS. **3**A-**3**B are understood to also apply to the corresponding features of the microphone **10**A in FIGS. **4**A-**4**B, except as described below. (45) The microphone **10**A differs from the microphone **10** in that the sensors **14**A are bent upward due to the material's residual stress or stress gradient thereof, resulting in an increased width of the gaps **16**A between sensors **14**A. Though FIGS. **4**A-**4**B show the sensors **14**A bent upward, in other examples, the sensors **14**A can bend downward due to material's residual stress or stress gradient thereof.

- (46) In use, the microphone **10**, **10**A is mounted on a printed circuit board (PCB) so that the substrate **12**, **12**A is disposed over or otherwise generally aligned with an opening in the PCB through which sound pressure enters the opening to deflect the sensors **14**, **14**A.
- (47) FIG. 5 shows a graph of sensitivity (in decibels or dB) versus frequency (in Hz). The solid line is representative of the performance of the microphone 10, where the sensors 14 are substantially planar (e.g. flat) and the gap 16 is substantially constant between the sensors 14 along their length. The dashed line is representative of the performance of the microphone 10A, where the sensors 14 along their length upward or downward and the width of the gap 16A varies between the sensors 14 along their length, which results in an increased reduction in acoustic resistance (e.g., because the gap 16A is larger). As shown in the graph, the performance of the microphone 10 provides better sensitivity in the low frequency range as compared to the performance of the microphone 10A. That is, changes in frequency in the low frequency range result in a smaller dB change for the microphone 10 than for the microphone 10A.
- (48) FIG. **6** shows a side view of one of the sensors **14** anchored on the substrate **12**. The sensor **14** has one or more sensing electrodes **15**A over a proximal portion thereof proximate to (e.g., adjacent) the substrate **12**. A distal portion **15**B of the sensors **14** distal of the sensing electrodes **15**A that extend to the free end of the sensors **14** do not have electrodes thereon. In one implementation, the distal portion **15**B of the sensors **14** only has a mechanical function (e.g., receiving acoustic pressure thereon and deflecting or moving based on such pressure). In another implementation, the sensing electrode **15**A extends at least partially into the distal portion **15**B. (49) Acoustic Device with Directional Reinforcement
- (50) With continued reference to FIG. **6**, the inventors have identified that increasing the rigidity of the distal portion **15**B of the sensors **14** can advantageously increase the ability of the cantilevered sensor **14** to resist deflection, for example, due to material internal stress gradient, without affecting the sensitivity of the sensor **14**. However, the inventors realized that increasing the rigidity of the distal portion **15**B of the sensor **14** by increasing the mass of the distal portion **15**B would negatively affect the operation of the sensor **14** as it affect the resonant frequency, where mass on the distal portion **15**B would reduce the frequency, thereby affecting the sensitivity of the sensor **14**.
- (51) FIGS. 7A-7C show a piezoelectric sensor **140** (hereafter "sensor") anchored to a substrate **120**. The sensor **140** can be incorporated into a piezoelectric MEMS microphone, such as the microphone **10** described above (e.g., the microphone can have multiple sensors **140** cantilevered relative to the substrate **120**, with gaps **16** between the sensors **140**). The sensor **140** can be cantilevered relative to the substrate as shown in FIG. **7**B.
- (52) The sensor **140** has a first portion **142** (e.g., proximal portion) that is proximate to (e.g., adjacent to) the substrate **120** and a second portion **145** (e.g., distal portion) that extends from the first portion **142** to a free end **146** (e.g., unsupported end) of the sensor **140**. The sensor **140** can have one or more electrodes (not shown) in the first portion **142** (e.g., that in one implementation do not extend into the second portion **145**). In some implementations, the sensors **140** can have one or more electrodes (not shown) in the first portion **142** that extend at least partially into the second

portion **145**. In some implementations, the sensor **140** can have multiple electrodes, for example, in the thickness direction of the sensor **140**. For example, the sensor **140** (e.g., a 1 μ m thick piezo layer) can have an electrode on top (e.g., on a top surface of the sensor beam), an electrode on bottom (e.g., on a bottom surface of the sensor beam) and/or an electrode in between a top surface and a bottom surface of the beam of the sensor **140**. In one implementation, the sensor **140** can be made of one layer of material. In another implementation, the sensor **140** can be made of multiple layers or films of materials, where the multiple layers have the same or different material stress gradients (e.g., due to the material property of the layer or film).

- (53) The second portion **145** of the sensor **140** has a corrugated section **147**. In the illustrated implementation, the corrugated section 147 has multiple (e.g. two) grooves or recesses 148 that are spaced apart from each other by a pitch P (e.g., where the grooves alternate with ridges or larger thickness portions of the beam) and extend generally in the same direction (X direction) as the beam B of the sensor 140. The grooves 148 can have a width W and depth D. In one implementation, the grooves **148** extend substantially parallel to a central longitudinal axis CL of the beam B. With reference to FIG. 7C, the grooves 148 can have a height H2 that is greater than a height H1 of side edges S of the beam B. In one implementation, the depth D of the grooves 148 is approximately twice the height H1 of the side edges S of the beam B. In one implementation, the depth D can be 1 µm. In one implementation, the height H2 of the grooves 148 is approximately double the height H1 of the side edges S of the beam B. One of skill will recognize that the corrugated section **147** can vary, for example, in the number of grooves **148**, angle of the grooves **148** relative to the center line CL of the beam B, length L, depth D, width W and/or pitch P of the grooves **148** and fall within the scope of the invention. In some implementations, the length L can be between about 100 um and about 1 mm. In some implementations, the depth D can be between about 0.1 um and about 10 um. In some implementations, the width W can be between about 0.1 um and about 20 um. In some implementations, the pitch P can be between about 0.2 um and about 100 um.
- (54) Advantageously, the corrugated section **147** with the groove(s) **148** extending generally in the same direction (X direction) as the length of the beam B increases the rigidity of the beam B in the longitudinal direction of the beam B and restricts deflection or bending of the beam B in the Z direction, for example in response to material internal stress gradient of the beam B. This results in a smaller gap **16** between the sensors **140** when subjected to the sound pressure. Additionally, because the corrugated section **147** reduces or limits the bending of the distal portion of the beam B, this results in little to no effect on bending of the proximal portion of the sensor **140**, and therefore it does not significantly affect the signal sensed by the electrodes of the sensor **140**. Further, the corrugated section **147** restricts deflection of the beam B in the Z direction without adding to the mass or weight of the second portion **145** of the sensor **140**. The corrugated section **147** allows the sensor **140** to deflect or bend in the width (or Y) direction of the beam B. Advantageously, the corrugated section **147** can result in a reduction of deflection of at least 20% (e.g., 20-60%) reduction as compared to a sensor without the corrugated section. (55) FIG. 7D shows a schematic cross-sectional side view of a piezoelectric sensor **140**′. Some of the features of the piezoelectric sensor **140**′ are similar to features of the piezoelectric sensor **140** in FIGS. 7A-7C. Thus, reference numerals used to designate the various components of the piezoelectric sensor **140**′ are identical to those used for identifying the corresponding components of the piezoelectric sensor 140 in FIGS. 7A-7C, except that an "'" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **140** in FIGS. 7A-7C are understood to also apply to the corresponding features of the piezoelectric sensor **140**′ in FIG. **7**D, except as described below.
- (56) The piezoelectric sensor **140**' differs from the piezoelectric sensor **140** in that the walls of the grooves **148**' extend at an angle α (e.g., a non-perpendicular angle) relative to the base of the grooves **148**'. In some implementations the angle α can be between 10 degrees and 90 degrees. In

- one implementation, the angle α can be between 60-70 degrees, such as about 60 degrees. Advantageously, the angle α of the grooves **148**' results in a more robust (e.g., stronger) corrugated section and inhibits defects therein.
- (57) FIG. 7E shows a schematic cross-sectional side view of a piezoelectric sensor **140**". Some of the features of the piezoelectric sensor **140**" are similar to features of the piezoelectric sensor **140**' in FIG. 7D. Thus, reference numerals used to designate the various components of the piezoelectric sensor **140**" are identical to those used for identifying the corresponding components of the piezoelectric sensor **140**' in FIG. 7D, except that an """ instead of an "" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **140**" in FIG. 7D are understood to also apply to the corresponding features of the piezoelectric sensor **140**" in FIG. 7E, except as described below.
- (58) The piezoelectric sensor **140**" differs from the piezoelectric sensor **140**' in that the walls of the grooves **148**" are not only inclined (extend at an angle, e.g., a non-perpendicular angle, relative to the base of the grooves **148**"), but the grooves **148**" are rounded. Advantageously, the rounded shape of the grooves **148**" of the corrugated section of the piezoelectric sensor **140**" can result in improved distribution of stress within the corrugated section (e.g., during operation of the sensor **140**") and improved reliability of the piezoelectric sensor **140**".
- (59) FIG. **8** shows a comparison of deflection (in μ m) between different piezoelectric sensor designs, namely a sensor **14** without any corrugation, a sensor **140** with a corrugated section similar to the corrugated section **147** described above, and a sensor **140**' with a corrugated section **147**' that has grooves **148**' extending generally transverse (e.g., perpendicular) to a longitudinal axis of the sensor **140**'. As shown in FIG. **8**, the sensor **140** with the corrugated section having grooves extended in the direction of the length of the beam has the smallest deflection, relative to the sensor **140** without any corrugation and relative to the sensor **140**' with the corrugated section **147**' with grooves **148**' extending generally transverse (e.g., perpendicular) to the longitudinal direction of the sensor **140**'.
- (60) FIG. **9** shows a graph of total displacement (in μ m) along the length of the beam (in m) for the sensors **14**, **140** and **140**′ shown in FIG. **8**. In the graph, zero on the X-axis corresponds to the location where the beam B joins the substrate (e.g. substrate **120**). FIG. **8** shows that the sensor **140** with the corrugated section **147** with grooves **148** extending in the same direction (X direction) as the length beam B exhibits a lower amount of deflection than the sensor **14** or sensor **140**′ (e.g., due to material internal stress gradient in the beam of the sensor). Additionally, as shown in FIG. **8**, the increased rigidity provided by the corrugated section **147** of the sensor **140** to the second portion (distal portion) of the sensor **140** results in the second (distal) portion of the sensor **140** maintaining a generally linear configuration.
- (61) FIG. **10** shows a comparison of output voltage from the sensor versus frequency for the sensors **14**, **140**, **140**' shown in FIG. **8**. FIG. **10** indicates that the inclusion of the corrugated section **147** in the sensor **140** has minimal impact on output voltage provided by the sensor **140**, as its output voltage increases by about 1% relative to the voltage performance of the sensor **14** without any corrugation. Accordingly, incorporation of the corrugated section **147** in the sensor **140**, as described above, has minimal impact on the performance of the sensor **140**.
- (62) FIGS. **11**A-**11**C show cross-sectional views of structures illustrating steps of a method **500** of manufacturing a piezoelectric sensor, like the sensor **140**, with a corrugated section, such as the corrugated section **147** described above. FIGS. **11**A-**11**C show cross-sections of the mold and beam in the widthwise direction (e.g., Y direction in FIGS. **7**A-**7**C).
- (63) FIG. **11**A shows the step of forming or providing **510** a corrugated mold. The mold can be made of silicon, but other suitable materials can be used.
- (64) FIG. **11**B shows the step of forming or depositing **520** a structure having one or more piezoelectric layers (e.g., one or more piezoelectric films) over the top surface of the mold to define the sensor beam with a proximal portion and a distal portion, the distal portion having a corrugated

- section including one or more grooves that correspond to the one or more grooves of the mold. For example, the one or more layers can be deposited onto the mold by one of many methods used for deposition of thin films, such as physical vapor deposition (PVD), Electron Beam Evaporation, Plasma Enhanced Chemical Vapor Deposition (PECVD), furnace deposition processes or a combination of these methods.
- (65) FIG. **11**C shows the step of releasing or removing **530** the structure with the corrugated section from the mold to form the cantilevered beam. Optionally, the method **500** of forming the piezoelectric sensor **140** with the cantilevered beam having the corrugated section **147** can be incorporated into a method for manufacturing a piezoelectric MEMS microphone. For example, the step of releasing or removing **530** the structure with the corrugated section from the mold can include leaving a portion of the sensor beam attached to a substrate in a cantilevered manner to provide the cantilevered sensor **140** with the corrugated section that can deflect, for example, when subjected to sound pressure.
- (66) FIGS. **12**A and **13**A show triangular shaped sensors **400**, **400**A anchored to a substrate **420**, **420**A along one edge. The sensor **400** is similar to the sensor **14** in FIG. **3**A and has no corrugated section. The sensor **400**A has a corrugated section **430**A with multiple (e.g., three) grooves **435**A that extend from the cantilevered or free end **410**A of the sensor **400**A toward the substrate **420**A. The grooves **435** of the corrugated section **430**A extend at a non-parallel angle relative to each other (e.g., joining proximate the free end **410**A and flaring out or diverging toward the substrate **420**A).
- (67) FIGS. 12B and 13B are graphs of total displacement (in um) along the length of the beam for the sensors 400, 400A shown in FIGS. 12A and 13A, respectively. In the graphs, the right hand side on the X-axis corresponds to the juncture between the sensors 400, 400A and their respective substrate 420, 420A. As shown in FIGS. 12B and 13B, the corrugated section 430A with non-parallel grooves 435A of the sensor 400A exhibits a lower total displacement than the sensor 400 that does not have a corrugated section. Advantageously, even where the grooves 435A extend in a non-parallel direction relative to each other, the sensor 400A with the corrugated section 430A exhibits a lower amount of deflection than the sensor 400 without a corrugated section (e.g., due to material internal stress gradient in the beam of the sensor). Additionally, the increased rigidity provided by the corrugated section 430A of the sensor 400A results in the second (distal) portion of the sensor 400A maintaining a generally linear configuration.
- (68) FIGS. **14**A-**14**E show different examples of corrugated sections that can be incorporated into a beam of a piezoelectric sensor (such as the sensors **140**, **400**, **400**A described above).
- (69) FIG. **14**A shows an example corrugated section **147**A with grooves **148**A**1**, **148**A**2**, **148**A**3** that are (linear and) angled relative to each other. In one example, the grooves **148**A**1**, **148**A**2**, **148**A**3** taper toward each other at one end and move away from each other at an opposite end. The corrugated section **147**A can be symmetrical about the center groove **148**A**2**.
- (70) FIG. 14B shows an example corrugated section 147B with three linear grooves 148B1, 148B2, 148B3 that are spaced apart from each other and extend parallel to each other, the groove 148B3 disposed between the other two grooves 148B1, 148B2. The corrugated section 147B also has a plurality of angled grooves 148B4 that interconnect the center groove 148B3 with the outer grooves 148B1, 148B2. The angled grooves 148B4 can extent at a non-parallel and non-perpendicular angle relative to the grooves 148B1, 148B2. For example, the angled grooves 148B4 can extend at an acute angle relative to the outer grooves 148B1, 148B2. Angled grooves 148B4 between the center groove 148B3 and outer groove 148B2 can extend generally at the same angle, and grooves 148B4 between the center groove 148B3 and outer groove 148B2 can extend generally at the same angle. The corrugated section 147B can be symmetrical about the center groove 148B3.
- (71) FIG. **14**C shows an example corrugated section **147**C with three linear grooves **148**C**1**, **148**C**2**, **148**C**3** that are spaced apart from each other and extend parallel to each other, the groove **148**C**3**

- disposed between the other two grooves 148C1, 148C2. The corrugated section 147C also has a plurality of first angled grooves 148C4 that interconnect the center groove 148C3 with the outer grooves 148C1, 148C2 and extend in one direction and a plurality of second angled grooves 148C5 that interconnect the center groove 148C3 with the outer grooves 148C1, 148C2 and extend in an opposite direction as the first angled grooves 148C4. The first and second angled grooves 148C4, 148C5 can extend at a non-parallel and non-perpendicular angle relative to the grooves 148C1, 148C2, 148C3. For example, the first angled grooves 148C4 can extend generally at the same angle relative to the outer grooves 148C1, 148C2 and the second angled grooves 148C5 can extend generally at the same angle relative to the outer grooves 148C1, 148C2. The corrugated section 147C can be symmetrical about the center groove 148C3.
- (72) FIG. **14**D shows an example corrugated section **147**D with two linear grooves **148**D**1**, **148**D**2** that are spaced apart from each other and extend parallel to each other. The corrugated section **147**D also has a plurality of angled grooves **148**D**3** that interconnect the grooves **148**D**1**, **148**D**2**. The angled grooves **148**D**3** can extend at a non-parallel and non-perpendicular angle relative to the grooves **148**D**1**, **148**D**2**. For example, the angled grooves **148**D**3** can extend at an acute angle relative to the grooves **148**D**1**. The angled grooves **148**D**3** between the grooves **148**D**1**, **148**D**2** can extend generally at the same angle.
- (73) FIG. **14**E shows an example corrugated section **147**E with two linear grooves **148**E**1**, **148**E**2** that are spaced apart from each other and extend parallel to each other. The corrugated section **147**E also has a plurality of curved grooves **148**E**3** that interconnect the grooves **148**E**1**, **148**E**2**. The curved grooves **148**E**3** can optionally be defined by a constant radius (e.g., have a circular curvature).
- (74) The sensors **140**, **410**A described above included corrugated sections **147**, **430**A to strengthen the distal portion of the sensors **140**, **410**A and reduce bending of the sensor **140**, **410**A (e.g., of the distal portion of the sensors **140**, **410**A). In other implementations, discussed below, beams can be added to the sensors (e.g., via an additive process) to reduce bending, such as where sensor resonant frequency reduction due to additional mass is not a concern.
- (75) FIG. **14**F shows a schematic top view of a piezoelectric sensor **400**F.
- (76) Some of the features of the piezoelectric sensor **400**F are similar to features of the piezoelectric sensor **400**A in FIG. **13**A. Thus, reference numerals used to designate the various components of the piezoelectric sensor **400**F are identical to those used for identifying the corresponding components of the piezoelectric sensor **400**A in FIG. **13**A, except that an "F" instead of an "A" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **400**A in FIG. **13**A are understood to also apply to the corresponding features of the piezoelectric sensor **14**F in FIG. **14**F, except as described below. (77) The piezoelectric sensor **400**F differs from the piezoelectric sensor **400**A in that the corrugated section **147**F includes multiple linear grooves **148**F of different lengths that are formed in the sensor **400**F, which has a triangular shape. Each of the grooves **148**F extends from a proximal end F1 to a distal end F2. In the illustrated implementation, all of the grooves **148**F have proximal ends F1 that are aligned with each other (e.g., end adjacent an imaginary straight line), and the distal end F2 of each of the grooves **148**F differs from the distal end F2 of at least one other of the grooves **148**F. The grooves **148**F can in some implementations have a cross-sectional shape similar to that of the grooves **148**, **148**′ or **148**″ in FIGS. 7C-7E.
- (78) FIG. **14**G shows a schematic top view of a piezoelectric sensor **400**G.
- (79) Some of the features of the piezoelectric sensor **400**G are similar to features of the piezoelectric sensor **400**F in FIG. **14**F. Thus, reference numerals used to designate the various components of the piezoelectric sensor **400**G are identical to those used for identifying the corresponding components of the piezoelectric sensor **400**F in FIG. **14**F, except that a "G" instead of an "F" has been added to the numerical identifier. Therefore, the structure and description for the

- various features of the piezoelectric sensor **400**F in FIG. **14**F, which is based on the description of the piezoelectric sensor **400**A, are understood to also apply to the corresponding features of the piezoelectric sensor **14**G in FIG. **14**G, except as described below.
- (80) The piezoelectric sensor **400**G differs from the piezoelectric sensor **400**F in that the corrugated section **147**G has multiple linear grooves **148**G of different lengths, where the proximal ends G1 of the grooves **148**G are not aligned (e.g., do not end adjacent an imaginary straight line). As shown in FIG. **14**G, the grooves **148**G closer to the centerline of the sensor **148**G have proximal ends G1 that are located distally of the proximal ends G1 of grooves **148**G closer to the side edges of the piezoelectric sensor **400**G. Such an arrangement (e.g., not aligned) of the proximal ends G1 of the grooves **148**G can advantageously inhibit the concentration of stress at the proximal ends G1 of the grooves **148**G. In one implementation, the proximal end G1 of one groove **148**G can be offset from the proximal end G1 of an adjacent groove **148**G by about 1 um to 2 um.
- (81) FIG. **14**H shows a schematic top view of a piezoelectric sensor **400**H. Some of the features of the piezoelectric sensor **400**H are similar to features of the piezoelectric sensor **400**F in FIG. **14**F. Thus, reference numerals used to designate the various components of the piezoelectric sensor **400**H are identical to those used for identifying the corresponding components of the piezoelectric sensor **400**F in FIG. **14**F, except that an "H" instead of an "F" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **400**F in FIG. **14**F, which is based on the description of the piezoelectric sensor **400**A, are understood to also apply to the corresponding features of the piezoelectric sensor **14**H in FIG. **14**H, except as described below.
- (82) The piezoelectric sensor **400**H differs from the piezoelectric sensor **400**F in that it includes edge grooves **148**H**2** that confine the distal ends of the linear grooves **148**H**1** (e.g., the distal ends H**2** of the linear grooves **148**H**1** end at the edge grooves **148**H**2**). The edge grooves **148**H**2** can optionally extend parallel to side edges of the piezoelectric sensor **400**H.
- (83) FIG. **14**I shows a schematic top view of a piezoelectric sensor **400**I.
- (84) Some of the features of the piezoelectric sensor **400**I are similar to features of the piezoelectric sensor **400**G in FIG. **14**G. Thus, reference numerals used to designate the various components of the piezoelectric sensor **400**I are identical to those used for identifying the corresponding components of the piezoelectric sensor **400**G in FIG. **14**G, except that an "I" instead of a "G" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **400**G in FIG. **14**G, which is based on the description of the piezoelectric sensor **400**A, are understood to also apply to the corresponding features of the piezoelectric sensor **14**I in FIG. **14**I, except as described below.
- (85) The piezoelectric sensor **400**I differs from the piezoelectric sensor **400**G in that it includes edge grooves **148**I**2** that confine the distal ends of the linear grooves **148**I**1** (e.g., the distal ends **12** of the linear grooves **148**I**1** end at the edge grooves **148**I**2**). The edge grooves **148**I**2** can optionally extend parallel to side edges of the piezoelectric sensor **400**I.
- (86) FIG. **14**J shows a schematic top view of a piezoelectric sensor **400**J.
- (87) Some of the features of the piezoelectric sensor **400**J are similar to features of the piezoelectric sensor **400**A in FIG. **13**A. Thus, reference numerals used to designate the various components of the piezoelectric sensor **400**J are identical to those used for identifying the corresponding components of the piezoelectric sensor **400**A in FIG. **13**A, except that a "J" instead of an "A" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **400**A in FIG. **13**A are understood to also apply to the corresponding features of the piezoelectric sensor **14**J in FIG. **14**J, except as described below. (88) The piezoelectric sensor **400**J differs from the piezoelectric sensor **400**A in that the corrugated section **147**J includes multiple linear grooves **148**J**1**, **148**J**2**, **148**J**3** of different lengths that are formed in the sensor **400**J, which has a triangular shape. The grooves **148**J**1**, **148**J**2**, **148**J**3** extend at an angle relative to a centerline of the piezoelectric sensor **400**J so that distal ends **J2** of each pair

- of grooves **148**J**1**, **148**J**2**, **148**J**3** join each other (e.g., in the shape of a V). In one implementation, the grooves **148**J**1**, **148**J**2**, **148**J**3** extend substantially parallel to one of the side edges of the piezoelectric sensor **400**J. The proximal ends J**1** of the grooves **148**J**1**, **148**J**2**, **148**J**3** are aligned with each other (e.g., end adjacent an imaginary straight line).
- (89) FIG. **14**K shows a schematic top view of a piezoelectric sensor **400**K.
- (90) Some of the features of the piezoelectric sensor **400**K are similar to features of the piezoelectric sensor **400**J in FIG. **14**J. Thus, reference numerals used to designate the various components of the piezoelectric sensor **400**K are identical to those used for identifying the corresponding components of the piezoelectric sensor **400**J in FIG. **14**J, except that a "K" instead of a "J" has been added to the numerical identifier. Therefore, the structure and description for the various features of the piezoelectric sensor **400**J in FIG. **14**J, which is based on the description of the piezoelectric sensor **400**A, are understood to also apply to the corresponding features of the piezoelectric sensor **14**K in FIG. **14**KG, except as described below.
- (91) The piezoelectric sensor **400**K differs from the piezoelectric sensor **400**J in that the corrugated section **147**K has multiple grooves **148**K**1**, **148**K**2**, **148**K**34** of different lengths and that extend at an angle relative to a centerline of the piezoelectric sensor **400**K so that distal ends K**2** of each pair of grooves **148**K**1**, **148**K**2**, **148**K**3** join each other (e.g., in the shape of a V). The proximal ends K**1** of the grooves **148**K**1**, **148**K**2**, **148**K**3** are not aligned (e.g., do not end adjacent an imaginary straight line). As shown in FIG. **14**K, the grooves **148**K**3** closer to the centerline of the sensor **148**K have proximal ends K**1** that are located distally of the proximal ends K**1** of grooves **148**K**1** closer to the side edges of the piezoelectric sensor **400**K. Such an arrangement (e.g., not aligned) of the proximal ends K**1** of the grooves **148**K**1**, **148**K**2**, **148**K**3** can advantageously inhibit the concentration of stress at the proximal ends K**1** of the grooves **148**K**1**, **148**K**2**, **148**K**3**. In one implementation, the proximal end K**1** of one groove **148**K**3** can be offset from the proximal end K**1** of an adjacent groove **148**K**2** by about 1 um to 2 um.
- (92) FIG. **15**A shows a top view of a piezoelectric sensor **640** (hereafter "sensor") with a proximal portion **642** and a distal portion **645**. One or more beams **648** can extend over the at least a portion of the distal portion **645**. In one implementation, the beam(s) **648** can extend linearly. In one implementation, the beam(s) **648** can be spaced apart from each other (e.g., at constant intervals) and extend parallel to each other. In one implementation, the beam(s) **648** can extend parallel to a central axis of the sensor **640**. The beam(s) **648** can strengthen the distal portion **645** of the sensor **640** to reduce bending of the sensor **640** (e.g., bending of the distal portion **645**), such as due to sound pressure.
- (93) The beam(s) **648** can in one implementation have a length of between 50 μ m and 500 μ m. In one implementation, the beam(s) **648** can have a width of between 0.1 μ m and 10 μ m. In one implementation, the beam(s) **648** can have a height of between 0.1 μ m and 1 μ m.
- (94) In one implementation, the beam(s) **648** can include a dielectric material, such as one or more of Silicon oxide, Silicon nitride, and silicon-oxynitrides; other suitable dielectric materials are possible. In one implementation, the beam(s) **648** can include a metal, such as aluminum (Al), copper (Cu), platinum (Pt), ruthenium (Ru), and Titanium (Ti); other suitable metals are possible. In one implementation, the beam(s) **148** can include a metal nitride, such as Tantalum Nitride (TaN), Titanium Nitride (TiN), Aluminum Nitride (AlN), and Scandium Aluminum Nitride (ScAlN); other suitable metal nitrides are possible. In one implementation the beam(s) **648** can include amorphous silicon.
- (95) FIG. **15**B shows a cross-section of the sensor **640** during a step in a manufacturing process (e.g., additive process) of the sensor **640**. The sensor **640** can be formed on a substrate **650**. The substrate **650** is optionally made of Silicon and may optionally have additional dielectric, metallic or semiconductor films deposited on it. The sensor beam **640** can be defined by one or more piezoelectric layers (e.g., one or more piezoelectric films) formed or deposited over the top surface of the substrate **650**. The one or more beam(s) **648** can be formed or deposited over a top surface of

- the sensor beam **640** (e.g., over the distal portion **645** of the sensor beam **640**) by depositing (e.g., sputtering) the material of the beam(s) **648** over the sensor beam **640** structure, and patterning of the material to form the beam(s) **648**.
- (96) FIG. **15**C shows the step of releasing or removing the sensor beam **640** with the beam(s) **648** on its top surface from the substrate **650**, leaving a portion **612** of the substrate **650** on either side of the cantilever sensor beam **640** (with the beams **648**) that can deflect, for example, when subjected to sound pressure. The portion **612** and sensor beam **640** forms a structure with a cavity through which sound pressure travels to the sensor beam **640**.
- (97) While certain embodiments of the inventions have been described, these embodiments have been presented by way of example only, and are not intended to limit the scope of the disclosure. Indeed, the novel methods and systems described herein may be embodied in a variety of other forms. Furthermore, various omissions, substitutions and changes in the systems and methods described herein may be made without departing from the spirit of the disclosure. The accompanying claims and their equivalents are intended to cover such forms or modifications as would fall within the scope and spirit of the disclosure. Accordingly, the scope of the present inventions is defined only by reference to the appended claims.
- (98) Features, materials, characteristics, or groups described in conjunction with a particular aspect, embodiment, or example are to be understood to be applicable to any other aspect, embodiment or example described in this section or elsewhere in this specification unless incompatible therewith. All of the features disclosed in this specification (including any accompanying claims, abstract and drawings), and/or all of the steps of any method or process so disclosed, may be combined in any combination, except combinations where at least some of such features and/or steps are mutually exclusive. The protection is not restricted to the details of any foregoing embodiments. The protection extends to any novel one, or any novel combination, of the features disclosed in this specification (including any accompanying claims, abstract and drawings), or to any novel one, or any novel combination, of the steps of any method or process so disclosed.
- (99) Furthermore, certain features that are described in this disclosure in the context of separate implementations can also be implemented in combination in a single implementation. Conversely, various features that are described in the context of a single implementation can also be implemented in multiple implementations separately or in any suitable subcombination. Moreover, although features may be described above as acting in certain combinations, one or more features from a claimed combination can, in some cases, be excised from the combination, and the combination may be claimed as a subcombination or variation of a subcombination. (100) Moreover, while operations may be depicted in the drawings or described in the specification
- in a particular order, such operations need not be performed in the particular order shown or in sequential order, or that all operations be performed, to achieve desirable results. Other operations that are not depicted or described can be incorporated in the example methods and processes. For example, one or more additional operations can be performed before, after, simultaneously, or between any of the described operations. Further, the operations may be rearranged or reordered in other implementations. Those skilled in the art will appreciate that in some embodiments, the actual steps taken in the processes illustrated and/or disclosed may differ from those shown in the figures. Depending on the embodiment, certain of the steps described above may be removed, others may be added. Furthermore, the features and attributes of the specific embodiments disclosed above may be combined in different ways to form additional embodiments, all of which fall within the scope of the present disclosure. Also, the separation of various system components in the implementations described above should not be understood as requiring such separation in all implementations, and it should be understood that the described components and systems can generally be integrated together in a single product or packaged into multiple products. (101) For purposes of this disclosure, certain aspects, advantages, and novel features are described

herein. Not necessarily all such advantages may be achieved in accordance with any particular

embodiment. Thus, for example, those skilled in the art will recognize that the disclosure may be embodied or carried out in a manner that achieves one advantage or a group of advantages as taught herein without necessarily achieving other advantages as may be taught or suggested herein. (102) Conditional language, such as "can," "could," "might," or "may," unless specifically stated otherwise, or otherwise understood within the context as used, is generally intended to convey that certain embodiments include, while other embodiments do not include, certain features, elements, and/or steps. Thus, such conditional language is not generally intended to imply that features, elements, and/or steps are in any way required for one or more embodiments or that one or more embodiments necessarily include logic for deciding, with or without user input or prompting, whether these features, elements, and/or steps are included or are to be performed in any particular embodiment.

(103) Conjunctive language such as the phrase "at least one of X, Y, and Z," unless specifically stated otherwise, is otherwise understood with the context as used in general to convey that an item, term, etc. may be either X, Y, or Z. Thus, such conjunctive language is not generally intended to imply that certain embodiments require the presence of at least one of X, at least one of Y, and at least one of Z.

(104) Language of degree used herein, such as the terms "approximately," "about," "generally," and "substantially" as used herein represent a value, amount, or characteristic close to the stated value, amount, or characteristic that still performs a desired function or achieves a desired result. For example, the terms "approximately", "about", "generally," and "substantially" may refer to an amount that is within less than 10% of, within less than 5% of, within less than 1% of, within less than 0.1% of, and within less than 0.01% of the stated amount. As another example, in certain embodiments, the terms "generally parallel" and "substantially parallel" refer to a value, amount, or characteristic that departs from exactly parallel by less than or equal to 15 degrees, 10 degrees, 5 degrees, 3 degrees, 1 degree, or 0.1 degree.

(105) The scope of the present disclosure is not intended to be limited by the specific disclosures of preferred embodiments in this section or elsewhere in this specification, and may be defined by claims as presented in this section or elsewhere in this specification or as presented in the future. The language of the claims is to be interpreted broadly based on the language employed in the claims and not limited to the examples described in the present specification or during the prosecution of the application, which examples are to be construed as non-exclusive. (106) Of course, the foregoing description is that of certain features, aspects and advantages of the present invention, to which various changes and modifications can be made without departing from the spirit and scope of the present invention. Moreover, the devices described herein need not feature all of the objects, advantages, features and aspects discussed above. Thus, for example, those of skill in the art will recognize that the invention can be embodied or carried out in a manner that achieves or optimizes one advantage or a group of advantages as taught herein without necessarily achieving other objects or advantages as may be taught or suggested herein. In addition, while a number of variations of the invention have been shown and described in detail, other modifications and methods of use, which are within the scope of this invention, will be readily apparent to those of skill in the art based upon this disclosure. It is contemplated that various combinations or subcombinations of these specific features and aspects of embodiments may be made and still fall within the scope of the invention. Accordingly, it should be understood that various features and aspects of the disclosed embodiments can be combined with or substituted for one another in order to form varying modes of the discussed devices.

Claims

1. A method of making a piezoelectric sensor for a piezoelectric microelectromechanical systems microphone, comprising: forming or providing a mold extending along a length and having two or

more grooves in a top surface of the mold, the two or more grooves extending in a direction of the length of the mold to a distal end of the mold, the two or more grooves diverging from each other along their lengths; forming or depositing a structure having one or more piezoelectric layers over the top surface of the mold to define a beam with a proximal portion and a distal portion, the distal portion having a corrugated section including two or more grooves that correspond to the two or more grooves of the mold; forming an electrode or applying an electrode to the proximal portion of the structure; and releasing the structure from the mold to form one or more cantilever beams.

- 2. The method of claim 1 wherein the beam has a triangular profile.
- 3. A method of making a piezoelectric sensor for a piezoelectric microelectromechanical systems microphone, comprising: forming or providing a mold extending along a length and having one or more grooves in a top surface of the mold, the one or more grooves extending in a direction of the length of the mold to a distal end of the mold; forming or depositing a structure having one or more piezoelectric layers over the top surface of the mold to define a beam with a proximal portion and a distal portion, the distal portion having a corrugated section including one or more grooves that correspond to the one or more grooves of the mold, a thickness of the beam between a top surface of the beam and a bottom surface of the beam being greater in the corrugated section than in the proximal portion of the beam; and releasing the structure from the mold to form one or more cantilever beams.
- 4. A method of making an electronic device, comprising: forming or providing a printed circuit board that includes a substrate layer; forming or providing one or more piezoelectric microelectromechanical systems microphones via a process including (a) forming or providing a mold extending along a length and having one or more grooves in a top surface of the mold, the one or more grooves extending in a direction of the length of the mold to a distal end of the mold, (b) forming or depositing a structure having one or more piezoelectric layers over the top surface of the mold to define a beam with a proximal portion and a distal portion, the distal portion having a corrugated section including one or more grooves that correspond to the one or more grooves of the mold, (c) forming an electrode or applying an electrode to the proximal portion of the structure, (d) releasing the structure from the mold, and (e) leaving a part of the structure attached to a substrate in a cantilevered manner to form a cantilever beam that deflects when subjected to sound pressure, a thickness of the beam between a top surface and a bottom surface being greater in the corrugated section than in the proximal portion of the beam; and mounting the one or more piezoelectric microelectromechanical systems microphones on the printed circuit board.
- 5. The method of claim 4 wherein the corrugated section has two or more grooves.
- 6. The method of claim 5 wherein the two or more grooves extend parallel to each other.
- 7. The method of claim 5 wherein the two or more grooves extend parallel to a central longitudinal axis of the beam.
- 8. The method of claim 4 wherein the two or more grooves diverge from each other along their lengths.
- 9. The method of claim 4 wherein the beam has a triangular profile.
- 10. The method of claim 3 wherein the corrugated section has two or more grooves.
- 11. The method of claim 10 wherein the two or more grooves extend parallel to each other.
- 12. The method of claim 10 wherein the two or more grooves extend parallel to a central longitudinal axis of the beam.
- 13. The method of claim 10 wherein the two or more grooves diverge from each other along their lengths.
- 14. The method of claim 10 wherein the beam has a triangular profile.